



EV549570797

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial-No. .... 10/615,051  
Filing Date ..... July 7, 2003  
Confirmation No. .... 7998  
Inventor ..... Brian A. Vaartstra  
Assignee ..... Micron Technology, Inc.  
Group Art Unit ..... 2823  
Examiner ..... Brook Kebede  
Attorney's Docket No. .... MI22-2308  
Customer No. .... 021567  
Title: Methods of Forming a Phosphorus Doped Silicon Dioxide-Comprising  
Layer (as Amended)

**RESPONSE TO MARCH 25, 2005 NOTICE OF ALLOWANCE**  
**PRELIMINARY AMENDMENT TO ACCOMPANY RCE FILING**

To: Mail Stop RCE  
Commissioner for Patents  
P. O. Box 1450  
Alexandria, VA 22313-1450

**VIA EXPRESS MAIL**

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)  
Wells St. John P.S.  
601 West First Avenue, Suite 1300  
Spokane, WA 99201-3828

Responsive to the Notice of Allowance dated March 25, 2005, Applicant  
amends and remarks as follows:

**AMENDMENTS**